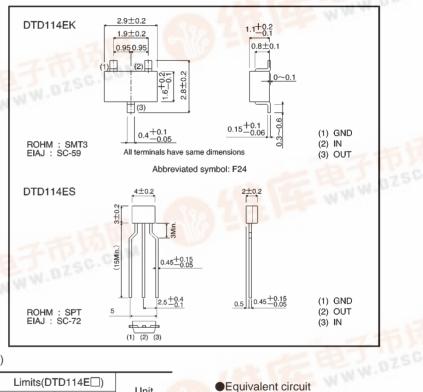
# Digital transistors (built-in resistors) DTD114EK / DTD114ES

## Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 2) The bias resistors consist of thinfilm resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- 3) Only the on/off conditions need to be set for operation, making device design easy.
- Structure NPN digital transistor (Built-in resistor type)

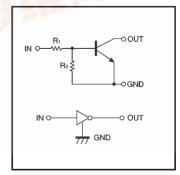
## External dimensions (Units: mm)



## ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits(D	Unit		
- raiailletei	Symbol	K	S	Offic	
Supply voltage	Vcc	50		V	
Input voltage	VIN	<del>-10~+40</del>		V	
Output current	lc	500		mA	
Power dissipation	Pd	200	300	mW	
Junction temperature	Tj	150		C	
Storage temperature	Tstg	−55~+150		°C	

# Equivalent circuit





### • Electrical characteristics (Ta = 25°C)

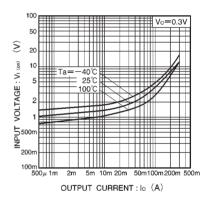
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Input voltage	VI(off)	_	_	0.5	V	Vcc=5V, Io=100 μA	
	VI(on)	3	_	_		Vo=0.3V, Io=10mA	
Output voltage	V <sub>O(on)</sub>	_	0.1	0.3	V	lo/li=50mA/2.5mA	
Input current	lı	_	_	0.88	mA	V <sub>I</sub> =5V	
Output current	IO(off)	_	_	0.5	μΑ	Vcc=50V, Vi=0V	
DC current gain	Gı	56	_	_	_	Vo=5V, Io=50mA	
Input resistance	R <sub>1</sub>	7	10	13	kΩ	_	
Resistance ratio	R2/R1	0.8	1	1.2	_	_	
Transition frequency	fτ	_	200	_	MHz	Vc=10V, I=-50mA, f=100MHz *	

<sup>\*</sup> Transition frequency of the device

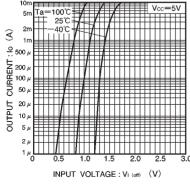
## Packaging specifications

	Package	SMT3	SPT
	Packaging type	Taping	Taping
	Code	T146	TP
Part No.	Basic ordering unit (pieces)	3000	5000
DTD114EK		0	_
DTD114ES		_	0

### Electrical characteristic curves



Input voltage vs. output current (ON characteristics)



(OFF characteristics)

5m 10m 20m 50m100m200m 500m OUTPUT CURRENT: lo (A) Fig.2 Output current vs. input voltage

Ō 200

100

50

20

10

CURRENT GAIN:

8

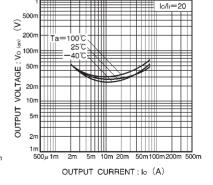


Fig.3 DC current gain vs. output current

100°C

25°C

Vo=5V

Fig.4 Output voltage vs. output current